TERMINATION CHIP 250 WATT



DATA SHEET PART SERIES: 82-3008 SHEET 1 OF 2 Dwg 82-3008

EN 13-3453

FEATURES

APPLICATIONS

Mobile Networks Wide Band Operation High Power Broadcast

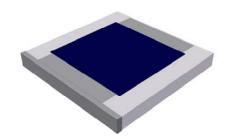
Direct Attached High Power Amplifiers

Low VSWR Isolators Military Easy Installation

Instrumentation



EMC Technology offers the widest selection of chip terminations worldwide. Chip components are offered in both thick and thin film resistive material and available in Alumina, Aluminum Nitride, Beryllium Oxide and CVD Diamond.



ORDERING INFORMATION

Part Identifier: 32-3008

SPECIFICATIONS

1.0 ELECTRICAL

Nominal Impedance: 50 ohms Frequency Range: DC - 1.0 GHz

VSWR: DC - 0.5 GHz 1.25:1 Max

0.5 - 1.0 GHz 1.35:1 Max

Input Power CW: 250 Watts @ 100°C heat sink, derated linearly to zero power and 150°C

Peak Power: 2500 Watts (based on 100us pulse width and 1% duty cycle)

DC Resistance: 50 Ω ±5%

2.0 ENVIRONMENTAL

Operating Temperature: -55°C to +150°C Non-operating Temperature: -65°C to +150°C Temperature Coefficient: +/-200 PPM / °C max

3.0 MARKING

Unit Marking: No Marking

4.0 QUALITY ASSURANCE

Visual and Mechanical Inspection: Per 824W107

DC Resistance Check: 100% DC Resistance Check

Data Retention: Standard

5.0 PACKAGING

Standard Packaging: Tray Packaging

smiths microwave Form 423F103 Rev-

Cage Codes: 24602 / 2Y194 Specifications are Subject to Change Without Notice

TERMINATION CHIP 250 WATT



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6.0 MECHANICAL

Substrate Material:

Beryllium Oxide

Resistive Film:

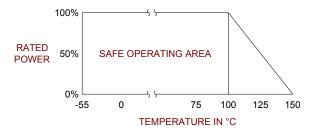
Thin Film

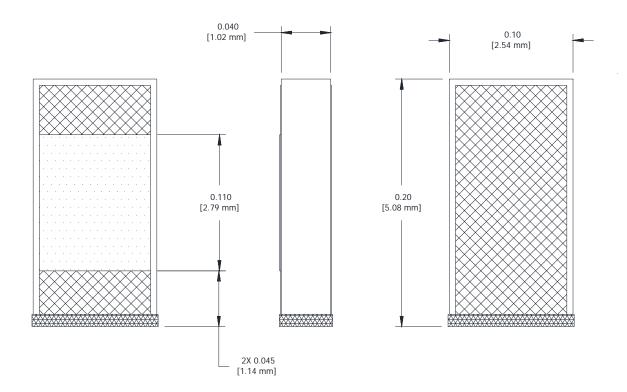
Terminal Material:

Tin/Lead

Metric Dimensions:

Provided for reference only





Unless Otherwise Specified: TOLERANCE: $X.XX = \pm 0.01$ $X.XXX = \pm 0.005$